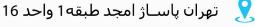






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BUT11/11A

High Voltage Power Switching Applications



NPN Silicon Transistor

1.Base 2.Collector 3.Emitter

Absolute Maximum Ratings $T_C=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage		V
	: BUT11	850	
	: BUT11A	1000	
V _{CEO}	Collector-Emitter Voltage		V
	: BUT11	400	
	: BUT11A	450	
V _{EBO}	Emitter-Base Voltage	9	V
I _C	Collector Current (DC)	5	А
I _{CP}	*Collector Current (Pulse)	10	А
l _B	Base Current (DC)	2	А
I _{BP}	*Base Current (Pulse)	4	А
P _C	Collector Dissipation (T _C =25°C)	100	W
T _J	Junction Temperature	150	°C
T _{STG}	Storage Temperature	- 65 ~ 150	°C

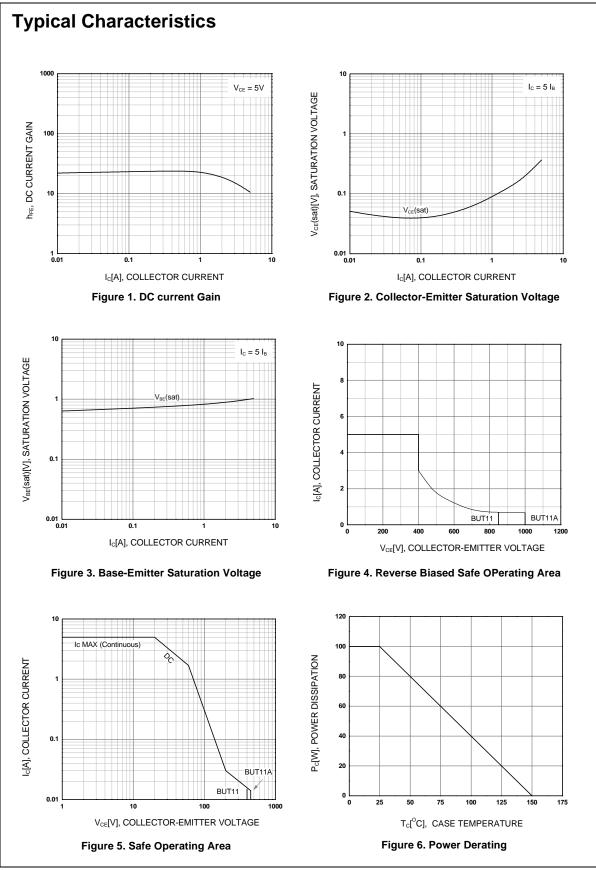
Electrical Characteristics T_C=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
V _{CEO} (sus)	* Collector-Emitter Sustaining Voltage : BUT11 : BUT11A	I _C = 100mA, I _B = 0	400 450			V V
I _{CES}	Collector Cut-off Current : BUT11 : BUT11A	V _{CE} = 850V, V _{BE} = 0			1 1	mA mA
I _{EBO}	Emitter Cut-off Current	$V_{BE} = 9V, I_{C} = 0$			10	mA
V _{CE} (sat)	Collector-Emitter Saturation Voltage : BUT11 : BUT11A	$I_C = 3A, I_B = 0.6A$ $I_C = 2.5A, I_B = 0.5A$			1.5 1.5	V V
V _{BE} (sat)	Base-Emitter Saturation Voltage : BUT11 : BUT11A	I _C = 3A, I _B = 0.6A I _C = 2.5A, I _B = 0.5A			1.3 1.3	V V
t _{ON}	Turn On Time	$V_{CC} = 250V, I_C = 2.5A$			1	μs
t _{STG}	Storage Time	$I_{B1} = -I_{B2} = 0.5A$			4	μs
t _F	Fall Time	$R_L = 100\Omega$			0.8	μs

^{*} Pulsed: pulsed duration = 300μs, duty cycle = 1.5%

Thermal Characteristics $T_C=25$ °C unless otherwise noted

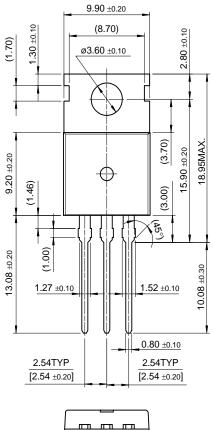
Symbol	Parameter	Тур	Max	Units
$R_{\theta jC}$	Thermal Resistance, Junction to Case		1.25	°C/W

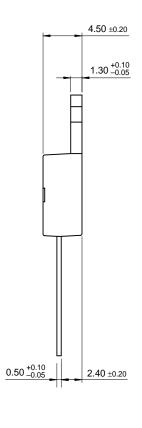


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Package Demensions

TO-220





10.00 ±0.20

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